

# NPN SILICON PLANAR MEDIUM POWER DARLINGTON TRANSISTORS

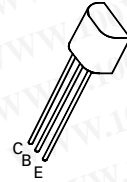
## ZTX600 ZTX601

ISSUE 2 - JUNE 94

### FEATURES

- \* 160 Volt  $V_{CEO}$
- \* 1 Amp continuous current
- \* Gain of 5K at  $I_C=1$  Amp
- \*  $P_{tot} = 1$  Watt

**勝特力材料 886-3-5753170**  
**勝特力电子(上海) 86-21-54151736**  
**勝特力电子(深圳) 86-755-83298787**  
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**E-Line  
TO92 Compatible**

### ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	ZTX600	ZTX601	UNIT
Collector-Base Voltage	$V_{CBO}$	160	180	V
Collector-Emitter Voltage	$V_{CEO}$	140	160	V
Emitter-Base Voltage	$V_{EBO}$	10		V
Peak Pulse Current	$I_{CM}$	4		A
Continuous Collector Current	$I_C$	1		A
Power Dissipation at $T_{amb}=25^\circ\text{C}$ derate above $25^\circ\text{C}$	$P_{tot}$	1	5.7	W mW/ $^\circ\text{C}$
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +200		$^\circ\text{C}$

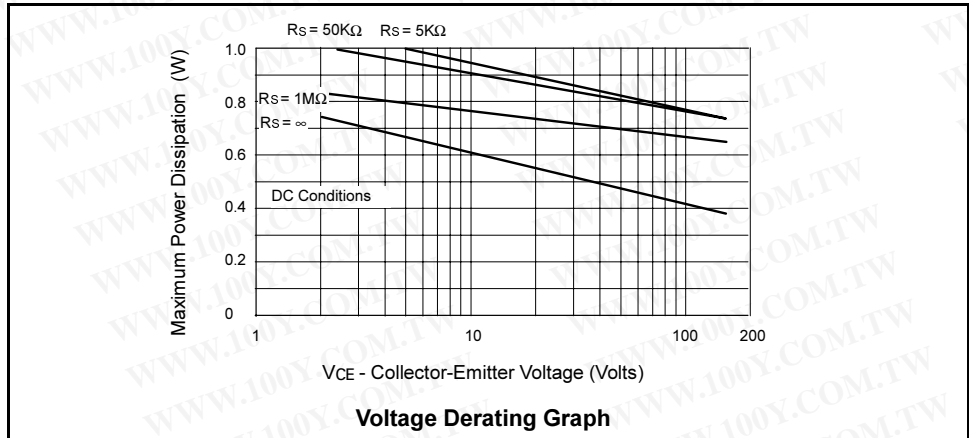
### ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL	ZTX600			ZTX601			UNIT	CONDITIONS.
		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	160			180			V	$I_C=100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	140			160			V	$I_C=10\text{mA}^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	10			10			V	$I_E=100\mu\text{A}$
Collector Cut-Off Current	$I_{CBO}$			0.01 10			0.01 10	$\mu\text{A}$ $\mu\text{A}$	$V_{CB}=140\text{V}$ $V_{CB}=160\text{V}$ $V_{CB}=140\text{V}, T_a=100^\circ\text{C}$ $V_{CB}=160\text{V}, T_a=100^\circ\text{C}$
Emitter Cut-Off Current	$I_{EBO}$			0.1			0.1	$\mu\text{A}$	$V_{EB}=8\text{V}$
Collector-Emitter Cut-Off Current	$I_{CES}$			10			10	$\mu\text{A}$ $\mu\text{A}$	$V_{CES}=140\text{V}$ $V_{CES}=160\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		0.75 0.85	1.1 1.2		0.75 0.85	1.1 1.2	V V	$I_C=0.5\text{A}, I_B=5\text{mA}^*$ $I_C=1\text{A}, I_B=10\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		1.7	1.9		1.7	1.9	V	$I_C=1\text{A}, I_B=10\text{mA}^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		1.5	1.7		1.5	1.7	V	$I_C=1\text{A}, V_{CE}=5\text{V}^*$

**ELECTRICAL CHARACTERISTICS (at T<sub>amb</sub> = 25°C unless otherwise stated).**

PARAMETER	SYMBOL	ZTX600			ZTX601			UNIT	CONDITIONS.
		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
Static Forward Current Transfer Ratio	h <sub>FE</sub>	1K			1K				I <sub>C</sub> =50mA, V <sub>CE</sub> =10V* I <sub>C</sub> =0.5A, V <sub>CE</sub> =10V* I <sub>C</sub> =1A, V <sub>CE</sub> =10V*
		2K		100K	2K		100K		
		1K			1K				
Group A		1K	2K		1K	2K			I <sub>C</sub> =50mA, V <sub>CE</sub> =10V* I <sub>C</sub> =0.5A, V <sub>CE</sub> =10V* I <sub>C</sub> =1A, V <sub>CE</sub> =10V*
		2K	5K	20K	2K	5K	20K		
		1K	3K		1K	3K			
Group B		5K	10K		5K	10K			I <sub>C</sub> =50mA, V <sub>CE</sub> =10V* I <sub>C</sub> =0.5A, V <sub>CE</sub> =10V* I <sub>C</sub> =1A, V <sub>CE</sub> =10V*
		10K	20K	100K	10K	20K	100K		
		5K	10K		5K	10K			
Transition Frequency	f <sub>T</sub>	150	250		150	250		MHz	I <sub>C</sub> =100mA, V <sub>CE</sub> =10V f=20MHz
Input Capacitance	C <sub>ibo</sub>		60	90		60	90	pF	V <sub>EB</sub> =0.5V, f=1MHz
Output Capacitance	C <sub>obo</sub>		10	15		10	15	pF	V <sub>CE</sub> =10V, f=1MHz
Switching Times	t <sub>on</sub>		0.75			0.75		μs	I <sub>C</sub> =0.5A, V <sub>CE</sub> =10V I <sub>B1</sub> =I <sub>B2</sub> =0.5mA
	t <sub>off</sub>		2.2			2.2		μs	

\*Measured under pulsed conditions. Pulse width=300μs. Duty cycle ≤2%



The maximum permissible operational temperature can be obtained from this graph using the following equation

$$T_{amb(max)} = \frac{Power(max) - Power(act)}{0.0057} + 25^\circ C$$

T<sub>amb(max)</sub> = Maximum operating ambient temperature

Power(max) = Maximum power dissipation figure, obtained from the above graph for a given V<sub>CE</sub> and source resistance (R<sub>S</sub>)

Power(actual) = Actual power dissipation in users circuit

# ZTX600 ZTX601

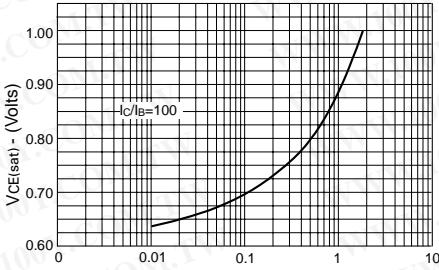
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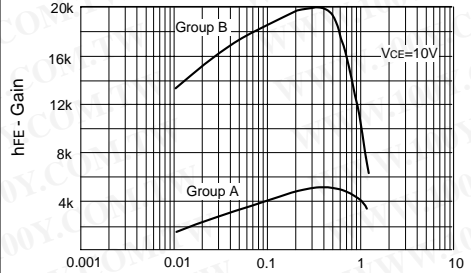
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## TYPICAL CHARACTERISTICS



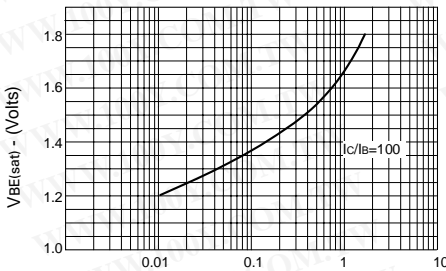
$I_C$  - Collector Current (Amps)

**$V_{CE(sat)}$  v  $I_C$**



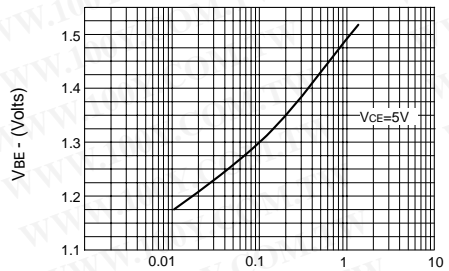
$I_C$  - Collector Current (Amps)

**$h_{FE}$  v  $I_C$**



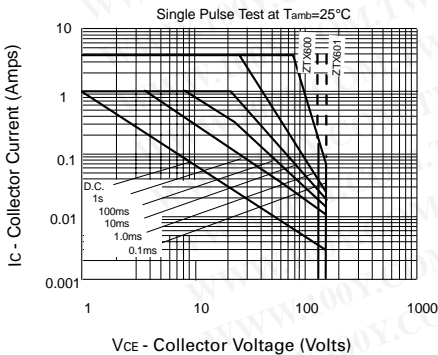
$I_C$  - Collector Current (Amps)

**$V_{BE(sat)}$  v  $I_C$**



$I_C$  - Collector Current (Amps)

**$V_{BE(on)}$  v  $I_C$**



$V_{CE}$  - Collector Voltage (Volts)

**Safe Operating Area**